



ELECTRONICS, INC.
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NTE2539
Silicon NPN Transistor
High Voltage, High Speed Switch

Features:

- High Breakdown Voltage and Reliability
- Fast Switching Speed
- Wide ASO

Absolute Maximum Ratings: ($T_A = +25^\circ\text{C}$ unless otherwise specified)

Collector–Base Voltage, V_{CBO}	500V
Collector–Emitter Voltage, V_{CEO}	400V
Emitter–Base Voltage, V_{EBO}	7V
Collector Current, I_C		
Continuous	25A
Peak (Note 1)	40A
Base Current, I_B	8A
Collector Dissipation, P_D		
$T_A = +25^\circ\text{C}$	2.5W
$T_C = +25^\circ\text{C}$	160W
Operating Junction Temperature, T_J	+150°C
Storage Temperature Range, T_{stg}	–55° to +150°C

Note 1. Pulse Test: Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 10\%$.

Electrical Characteristics: ($T_A = +25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cutoff Current	I_{CBO}	$V_{CB} = 400\text{V}$, $I_E = 0$	–	–	10	μA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = 5\text{V}$, $I_C = 0$	–	–	10	μA
DC Current Gain	h_{FE}	$V_{CE} = 5\text{V}$, $I_C = 3.2\text{A}$	15	–	50	
		$V_{CE} = 5\text{V}$, $I_C = 16\text{A}$	10	–	–	
		$V_{CE} = 5\text{V}$, $I_C = 10\text{mA}$	10	–	–	
Collector–Emitter Saturation Voltage	$V_{CE(\text{sat})}$	$I_C = 16\text{A}$, $I_B = 3.2\text{A}$	–	–	0.8	V
Base–Emitter Saturation Voltage	$V_{BE(\text{sat})}$	$I_C = 16\text{A}$, $I_B = 3.2\text{A}$	–	–	1.5	V

Electrical Characteristics (Cont'd): ($T_A = +25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Gain-Bandwidth Product	f_T	$V_{CE} = 10\text{V}$, $I_C = 3.2\text{A}$	—	20	—	MHz
Output Capacitance	C_{ob}	$V_{CB} = 10\text{V}$, $f = 1\text{MHz}$	—	300	—	pF
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 1\text{mA}$, $I_E = 0$	500	—	—	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 10\text{mA}$, $R_{BE} = \infty$	400	—	—	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 1\text{mA}$, $I_C = 0$	7	—	—	V
Collector-Emitter Sustaining Voltage	$V_{CEX(\text{sus})}$	$I_C = 10\text{A}$, $I_{B1} = 1\text{A}$, $I_{B2} = -4\text{A}$, $L = 200\mu\text{H}$ Clamped	400	—	—	V
Turn-On Time	t_{on}	$I_C = 20\text{A}$, $I_{B1} = 4\text{A}$, $I_{B2} = -8\text{A}$, $R_L = 10\Omega$, $V_{CC} = 200\text{V}$	—	—	0.5	μs
Storage Time	t_{stg}		—	—	2.5	μs
Fall Time	t_f		—	—	0.3	μs

